

Ferromagnetism of Diluted Semiconductor $\text{TiO}_{2-\delta}$ Thin Films Doped by Fe and Co

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It has been reported a lot of study focused on oxide materials that show ferromagnetism with higher Curie temperature compared to existing III-V and II-VI semiconducting compounds. Recently, TiO_2 doped with transition-metal elements such as Fe, Co, and Ni were found to exhibit ferromagnetism above room temperature. Although such diluted magnetic semiconductors (DMSs) have been under remarkable attention recently, the results reported by different research groups are frequently controversial on the origin of the exhibited ferromagnetic properties.

In this work, magnetic and electronic properties of Fe- and Co-doped $\text{TiO}_{2-\delta}$ thin films were investigated by vibrating sample magnetometer (VSM), Mössbauer spectroscopy, X-ray photoelectron spectroscopy (XPS), and Hall measurements. Anatase TiO_2 thin films were deposited on $\text{Al}_2\text{O}_3(0001)$ substrates by a sol-gel method employing spin-coating process. The precursor solution was prepared by dissolving titanium butoxide, $\text{Ti}[\text{O}(\text{CH}_2)_3\text{CH}_3]_4$, in 2-methoxyethanol at 70 °C.

When the precursor films were annealed in air, the resultant $\text{TiO}_2:\text{Fe}$ and $\text{TiO}_2:\text{Co}$ films were found to become electrically insulating. Also, no ferromagnetic properties were observed in those films. On the other hand, when the precursor films were annealed in vacuum, the resulting oxygen-deficient $\text{TiO}_{2-\delta}:\text{Fe}$ and $\text{TiO}_{2-\delta}:\text{Co}$ films were found to become semiconducting with p-type carriers in the 10^{18} cm^{-3} range obtained by Hall measurements. The oxygen-deficient films go through conductivity transition from n to p by Fe and Co doping. The results of VSM measurements on these $\text{TiO}_{2-\delta}:\text{Fe}$ and $\text{TiO}_{2-\delta}:\text{Co}$ films are shown in Fig. 1, exhibiting ferromagnetic behavior. Such ferromagnetic properties are found to disappear for highly Fe- or Co-doped films.

XPS measurements on the Fe- and Co-doped $\text{TiO}_{2-\delta}$ films reveal that Fe ions have both Fe^{2+} and Fe^{3+} ionic valences while Co ions have Co^{2+} mostly, as shown in Fig. 2. Mössbauer measurements on $\text{TiO}_{2-\delta}:\text{Fe}$ films also reveal the change of the magnetic properties with Fe composition.

Reference

- [1] H. M. Lee, S. J. Kim, I. Shim, and C. S. Kim, IEEE Trans. Magn. 39, 2788(2003).

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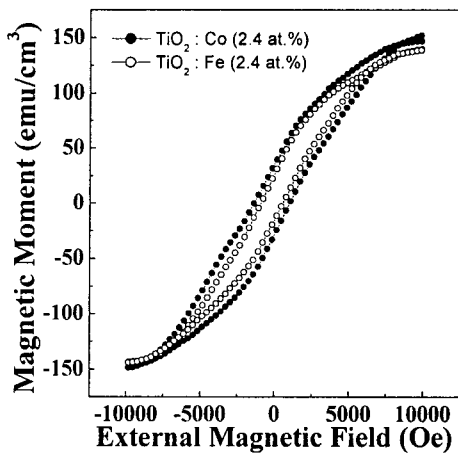


Fig. 1. Results of VSM measurements on anatase TiO₂:Fe and TiO₂:Co films with Fe and Co concentration of 2.4 at.%.

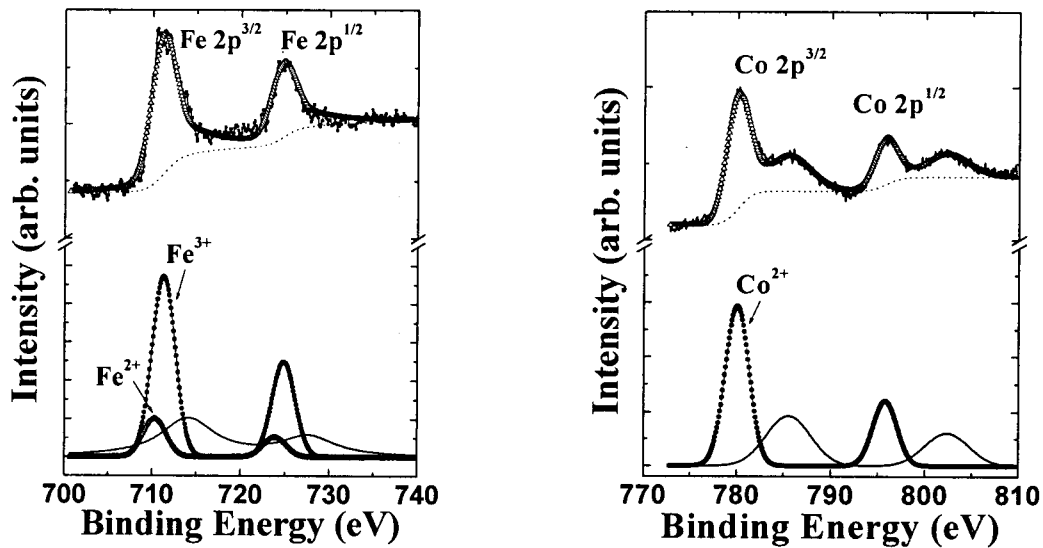


Fig. 2. Results of XPS measurements on TiO₂:Fe and TiO₂:Co films with Fe and Co concentration of 12 and 15 at.%, respectively.